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FDP8878

N-Channel Logic Level PowerTrench[®] MOSFET 30V, 40A, 15m Ω

General Descriptions

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{DS(ON)}$ and fast switching speed.

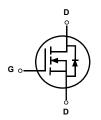
Features

- $r_{DS(ON)} = 15mΩ$, $V_{GS} = 10V$, $I_D = 40A$
- $r_{DS(ON)} = 19m\Omega$, $V_{GS} = 4.5V$, $I_D = 36A$
- High performance trench technology for extremely low r_{DS(ON)}
- Low gate charge
- High power and current handling capability
- RoHS Compliant





TO-220AB FDP SERIES



MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units		
V_{DSS}	Drain to Source Voltage	30	V		
V_{GS}	Gate to Source Voltage		±20	V	
I _D	Drain Current				
	Continuous ($T_C = 25^{\circ}C$, $V_{GS} = 10V$)	40	Α		
	Continuous (T _C = 25°C, V _{GS} = 4.5V)	36	Α		
	Pulsed	(Note 4)	141	Α	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	L = 1mH, I _{AS} = 11A	60	mJ	
		$L = 43\mu H, I_{AS} = 32A$	22	7 1113	
P _D	Power dissipation		40.5	W	
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C	

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case (Note 2)	3.7	°C/W
R _{e,IA}	Thermal Resistance, Junction to Ambient at 1000 seconds (Note 3)	43	°C/W

Package Marking and Ordering Information

Device Marking Device		Package Reel Size		Tape Width	Quantity
FDP8878	FDP8878	TO-220	Tube	n/a	45 units
		l.	l.	l.	

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	30	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temp. Coefficient	$I_D = 250\mu A$, Referenced to $25^{\circ}C$		21		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 24V V _{GS} = 0V	-	-	1 250	μА
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V	-	-	±100	nA
On Chara	cteristics			•	•	•
V _{GS(TH)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	1.2	1.7	2.5	V
$\frac{\Delta V_{GS(TH)}}{\Delta T_{J}}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		-5		mV/ºC
-		I _D = 40A, V _{GS} = 10V	-	12	15	
r	Drain to Source On Posistance	$I_D = 36A, V_{GS} = 4.5V$	-	16	19	mΩ
r _{DS(ON)}	Drain to Source On Resistance	I _D = 40, V _{GS} = 10V, T _A = 175°C	-	20	25	- 11122
Dynamic	Characteristics					
C _{ISS}	Input Capacitance	., ,-,,,	-	927	1235	pF
C _{OSS}	Output Capacitance	→V _{DS} = 15V, V _{GS} = 0V, → f = 1MHz	-	188	250	pF
C _{RSS}	Reverse Transfer Capacitance	- 11VII 12	-	1130	175	pF
R _G	Gate Resistance	f = 1MHz		3.0		Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V_{GS} = 0V to 10V V_{DD} = 15V	-	17.1	23	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0V \text{ to } 5V \mid I_D = 40A$	-	9.2	12	nC
Q _{gs}	Gate to Source Gate Charge	I _g = 1.0mA	-	2.6	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau	7	-	1.7	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	3.7	-	nC
Switching	Characteristics (V _{GS} = 10V)					
t _{ON}	Turn-On Time		-	255	383	ns
t _{d(ON)}	Turn-On Delay Time	7	-	11.1		ns
t _r	Rise Time	V _{DD} = 15V, I _D = 40A	-	244		ns
t _{d(OFF)}	Turn-Off Delay Time	V_{GS} = 10V, R_{GS} = 16 Ω	-	14.8		ns
t _f	Fall Time	7	-	35.3		ns
t _{OFF}	Turn-Off Time		-	50	75	ns
Drain-Soເ	urce Diode Characteristics					
Van	Source to Drain Diode Voltage	I _{SD} = 40A	-	1.1	1.25	V
V _{SD}	Source to Brain Blode Voltage	I _{SD} = 3.2A	-	0.85	1.2	V
t _{rr}	Reverse Recovery Time	$I_{SD} = 40A, dI_{SD}/dt = 100A/\mu s$	-	14.4	18.8	ns
Q_{RR}	Reverse Recovered Charge	$I_{SD} = 40A, dI_{SD}/dt = 100A/\mu s$	-	5.1	6.7	nC

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Starting T_J = 25°C, V_{DD} = 30V, V_{GS} = 10V
 R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θJA} is determined by the user's board design.
 R_{θJA} is measured with 1.0 in² copper on FR-4 board
 Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%

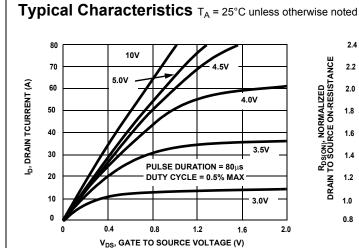


Figure 1. On Region Characteristics

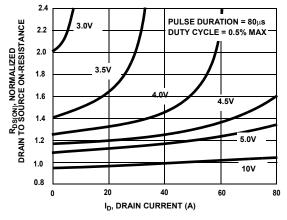


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

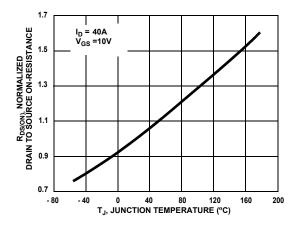


Figure 3. On Resistance Variation with Temperature

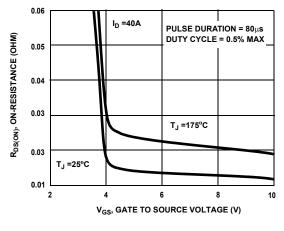


Figure 4. On-Resistance Variation with Gate-to-Source Votlage

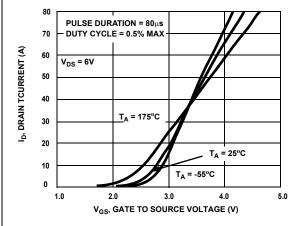


Figure 5. Transfer Characteristics

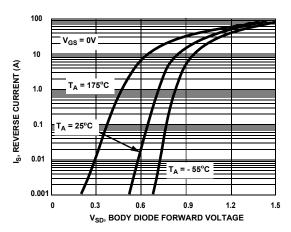
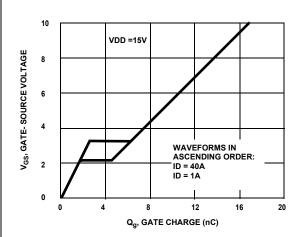


Figure 6. Body Diode Forward Voltage Variation With Source Current and Temperature

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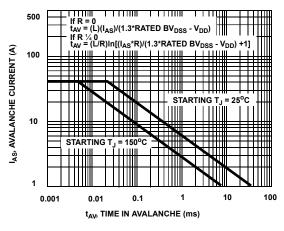


Typical Characteristics T_A = 25°C unless otherwise noted

10000

Figure 7. Gate Charge Characteristics

Figure 8. Capacitance Characteristics



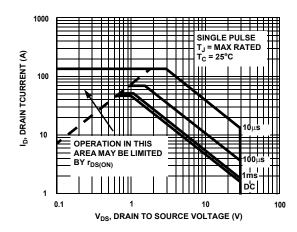
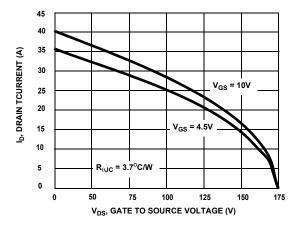


Figure 9. Unclamped Inductive Switching Capability

Figure 10. Safe Operating Area



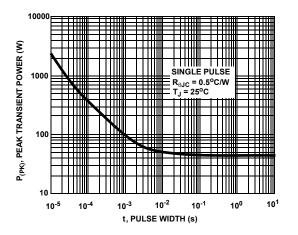


Figure 11. Maximum Continuous Drain Current vs Case Temperature

Figure 12. Single Pulse Maximum Power Dissipation

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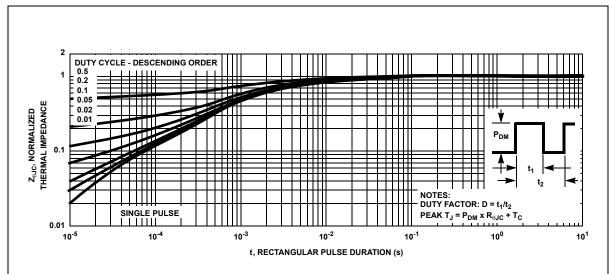


Figure 13. Transient Thermal Response Curve

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